

## TO-220F Plastic-Encapsulate Transistors

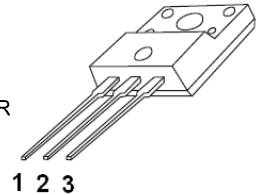
### 3CA2050 TRANSISTOR (PNP)

#### FEATURES

- High Breakdown Voltage
- General Purpose Switching and Amplification

TO – 220F

1. BASE
2. COLLECTOR
3. EMITTER



#### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	-180	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-160	V
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V
I <sub>C</sub>	Collector Current	-1.5	A
P <sub>C</sub>	Collector Power Dissipation	1.5	W
R <sub>θJA</sub>	Thermal Resistance From Junction To Ambient	83	°C/W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~+150	°C

#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-1mA, I <sub>E</sub> =0			-180	V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =0			-160	V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-100μA, I <sub>C</sub> =0			-6	V
Collector cut-off current	I <sub>CB0</sub>	V <sub>CB</sub> =-180V, I <sub>E</sub> =0			-10	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-6V, I <sub>C</sub> =0			-10	μA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-0.2A			240	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1.5A			50	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA			-1	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-0.05A			50	MHz

#### CLASSIFICATION OF h<sub>FE(1)</sub>

RANK R		O
RANGE	60-140	100-240